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40V N-Channel PowerTrench[®] MOSFET

General Description

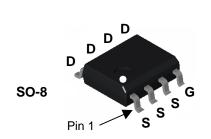
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $R_{DS(ON)}$ and fast switching speed.

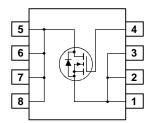
Applications

• DC/DC converter

Features

- 10.8 A, 40 V. $R_{\text{DS(ON)}}$ = 12 m Ω @ V_{GS} = 10 V
- Low gate charge (29 nC)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		40	V
V _{GSS}	Gate-Source Voltage		+30/-20	V
ID	Drain Current – Continuous	(Note 1a)	10.8	А
	– Pulsed		45	
PD	Power Dissipation for Single Operation	(Note 1a)	2.5	W
		(Note 1b)	1.4	
		(Note 1c)	1.2	
T_J, T_{STG}	Operating and Storage Junction Temperature Range		-55 to +175	°C
Therma	I Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	50	°C/W
$R_{\theta J A}$	Thermal Resistance, Junction-to-Ambient	(Note 1c)	125	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	25	°C/W

Package Marking and Ordering Information

Device	Reel Size	Tape width	Quantity
FDS4480	13"	12mm	2500 units
-			

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FDS4480

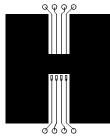
May 2013

	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-Sc	burce Avalanche Ratings (Note 2	2)				
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, V _{DD} =40V, I _D =10.8A			240	mJ
I _{AS}	Drain-Source Avalanche Current				10.8	А
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	40			V
<u>ΔBV_{DSS}</u> ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25°C		42		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
	Gate–Body Leakage, Forward	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
	acteristics (Note 2)			1		
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2	3.9	5	V
$\Delta V_{GS(th)}$ $\Delta V_{GS(th)}$ ΔT_{J}	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-8	5	mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$V_{GS} = 10 \text{ V}, I_D = 10.8 \text{ A}$ $V_{GS} = 10 \text{ V}, I_D = 10.8 \text{ A}, T_J=125^{\circ}\text{C}$		8 13	12 21	mΩ
I _{D(on)}	On–State Drain Current	$V_{GS} = 10 \text{ V}, V_{DS} = 5 \text{ V}$	22			A
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, I_D = 10.8 \text{ A}$		36		S
-						-
C _{iss}	Characteristics			1686		pF
C _{iss} C _{oss}	Output Capacitance	$V_{DS} = 20 V$, $V_{GS} = 0 V$, f = 1.0 MHz		384		pF pF
C _{oss} C _{rss}	Reverse Transfer Capacitance			185		pF pF
	•			105		рі
	g Characteristics (Note 2)			40		
t _{d(on)}	Turn-On Delay Time			12	22	ns
t _r	Turn–On Rise Time	VGS = 10 V, T(GEN = 0 11		9	18	ns
t _{d(off)}	Turn–Off Delay Time Turn–Off Fall Time	-		30 15	48 27	ns
t _f	Total Gate Charge	$V_{DS} = 20 \text{ V}, I_D = 10.8 \text{ A},$		29	41	ns nC
Q _g	Gate-Source Charge	$V_{DS} = 20 V$, $I_D = 10.8 A$, $V_{GS} = 10 V$		8.7	41	nC
Q _{gs} Q _{qd}	Gate-Drain Charge			8.0		nC
⊲gd	Gate-Drain Gharge			0.0		no

	Devenuetor	Test Conditions	N4:	T	Max	L lusito
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-S	ource Diode Characteristics a	and Maximum Ratings				
Is	Maximum Continuous Drain–Source Diode Forward Current				2.1	А
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 2.1 A$ (Note 2)		0.7	1.2	V
t _{rr}	Diode Reverse Recovery Time	$I_F = 10.8 \text{ A}, d_{iF}/d_t = 100 \text{ A}/\mu\text{s}$		27		nS
Q _{rr}	Diode Reverse Recovery Charge			58		nC

Notes:

1. R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{8JC} is guaranteed by design while R_{8CA} is determined by the user's board design.



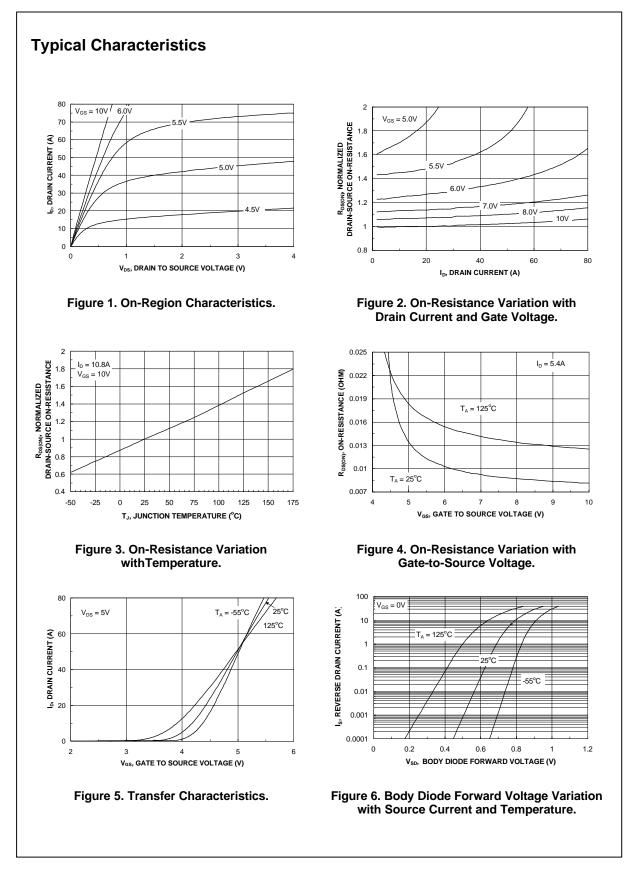
a) 50°C/W when mounted on a 1in² pad of 2 oz copper

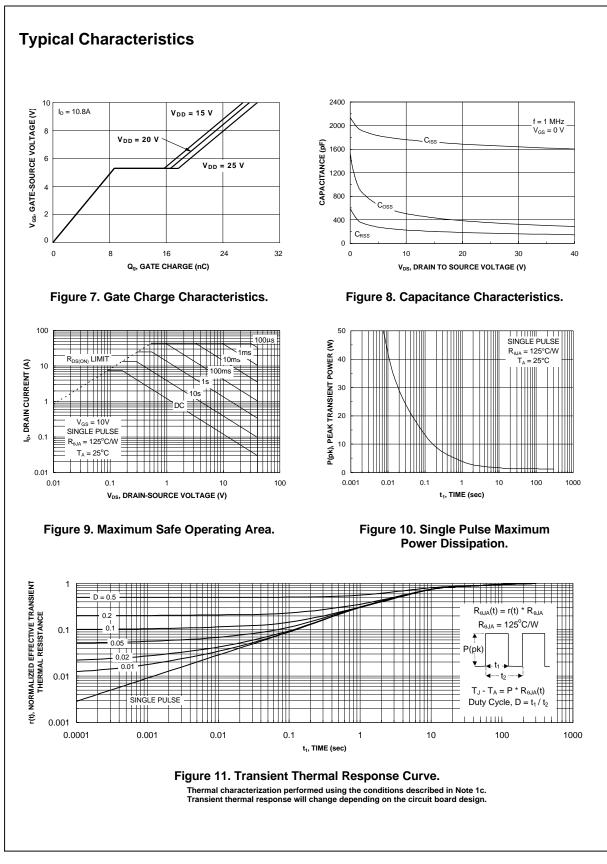


b) 105°C/W when mounted on a .04 in² pad of 2 oz copper c) 125°C/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%





FDS4480 Rev D1 (W)



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